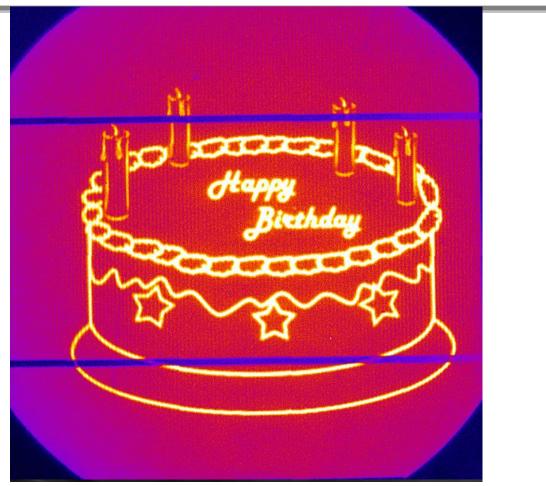
# Happy birthday PL Imaging!



SPREE Seminar – 15 December 2016





- The importance of good upbringing...
- Born in AUS, a healthy baby!
- Baby step, finding your place in the world.
- Now an adolescent, "knowing it all...". BORNIN AUS
  - but yet a lot to learn!







## The importance of "good upbringing".

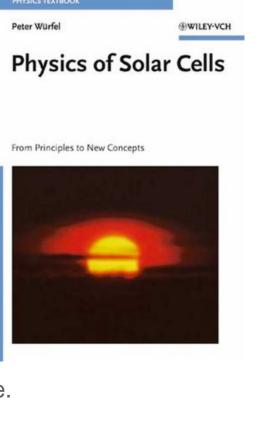




#### Prof Peter Würfel Universität Karlsruhe, Germany

- Lifetime achievements in the "Physics of Solar cells".
- Early adopter, recognizing the potential of luminescence.
- "Grandfather" of PL imaging!







#### Some background

• The generalised Planck equation:

$$dr_{sp}(\hbar\omega,T) = \frac{(\hbar\omega)^2 \cdot n^2}{\pi^2 \hbar^3 c_0^2} \cdot \alpha_{BB}(\hbar\omega,T) \cdot \frac{1}{\exp\left(\frac{\hbar\omega - \Delta\eta}{kT}\right)} d(\hbar\omega)$$
  
Emission spectrum is determined  
by the absorption properties.  
Emission intensity is determined by  
the separation of the quasi Fermi  
energies.

W. van Roosbroeck and W. Shockley, Phys.Rev. 94, 1558 (1954). P. Würfel, J. Phys. C 15, 3967 (1982).





#### Some background

$$I_{lum} \sim \exp\left(\frac{\Delta \eta - \hbar \omega}{kT}\right) \sim \exp\left(\frac{\Delta \eta}{kT}\right)$$

Quantitative information about Δη from PL intensity!
 Implied voltage measurements.

$$I_{lum} \sim n \cdot p = \Delta n \cdot (\Delta n + N_{A/D}) = n_i^2 \cdot \exp\left(\frac{\Delta \eta}{kT}\right)$$



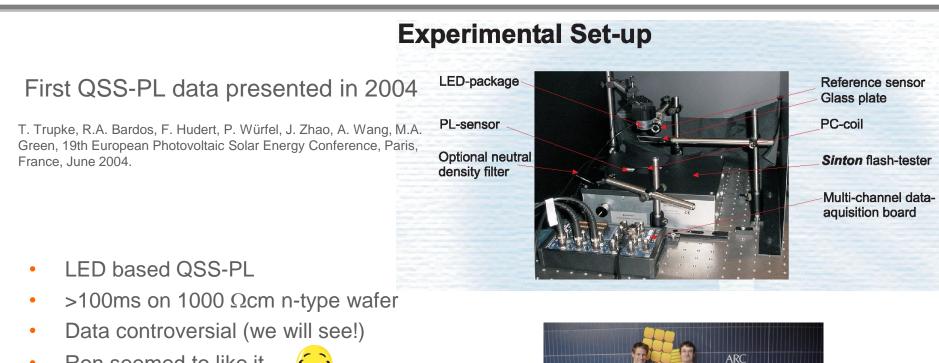
Quantitative information about  $\Delta n$  from PL intensity!

QSS-PL minority carrier lifetime measurements.





#### Early days...



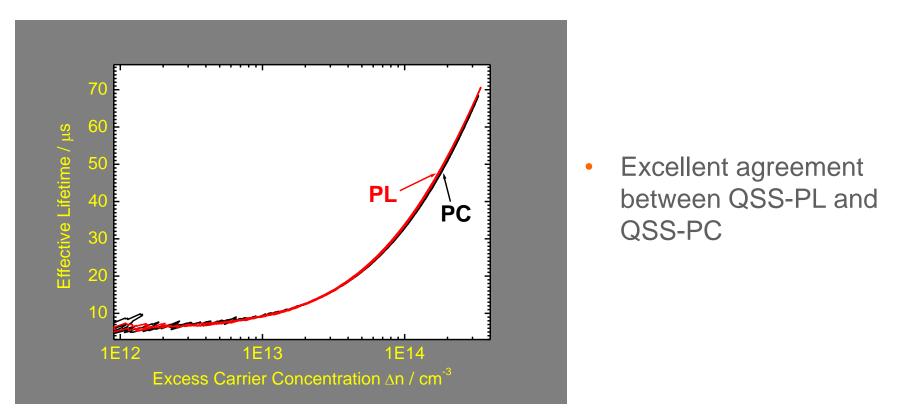
Ron seemed to like it...







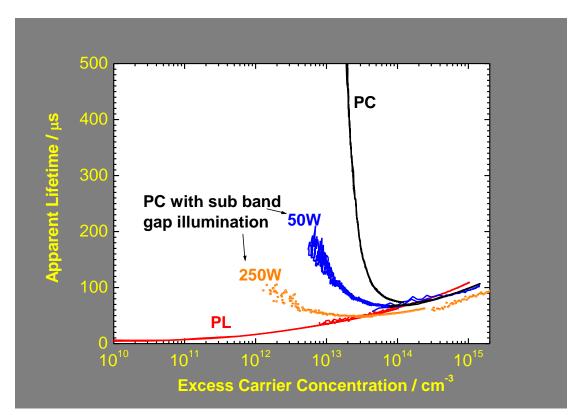
#### 2004: QSS-PL lifetime







#### 2004: QSS-PL lifetime

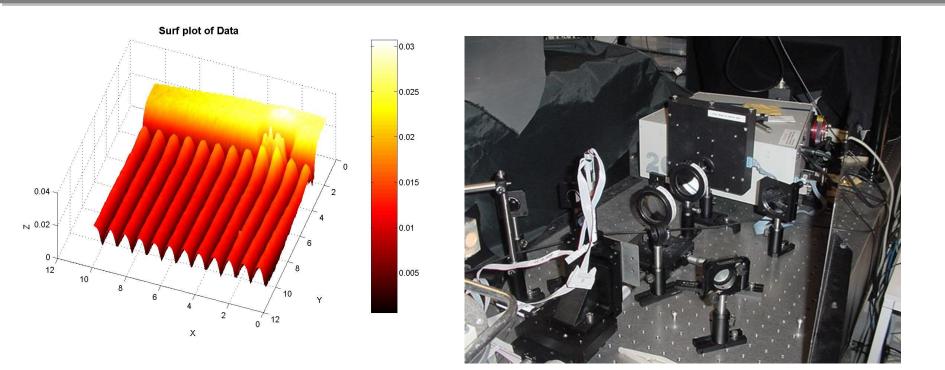


- QSS-PL immune to trapping.
- Calibration not trivial.
- QSS-PC still most widely used today.
- Complementary techniques.





## 2004 – PL mapping



- Scanning spectral PL tool, 50mm x 50mm, micron resolution.
- Slow

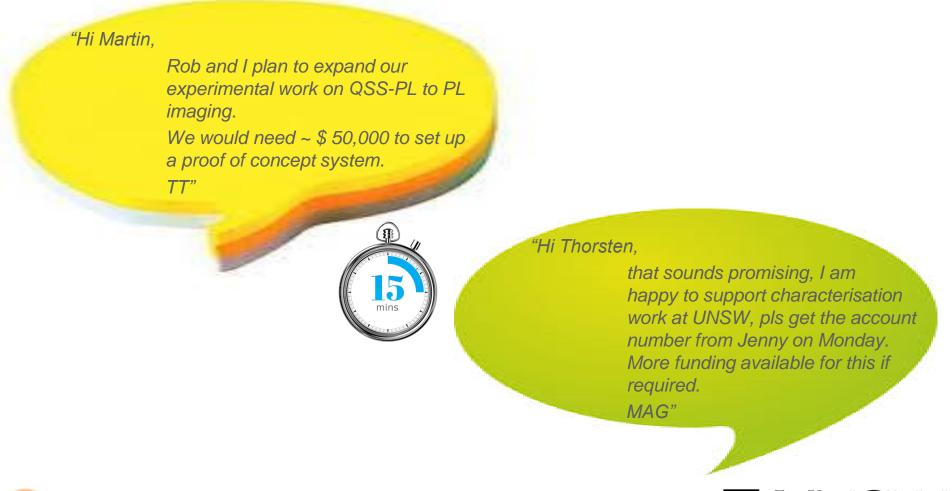
"Let's try camera based PL imaging!"





#### May 2005 – Can we actually afford this?

A weekend email makes all the difference





## Making it happen - quickly!

Mid 2005: First PL imaging prototype in EE building, LG 24.



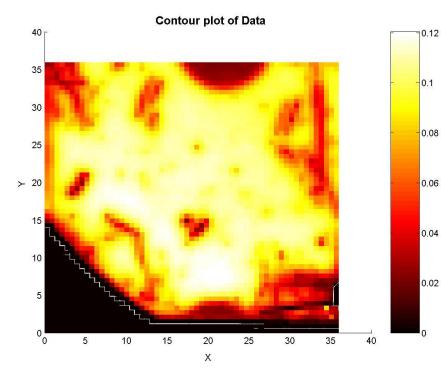


- The 100W laser challenge...
- The mapping tool had to go...
- First PL image, a Eureka moment!
- Huge Excitement for months.
- System is still in operation at UNSW.

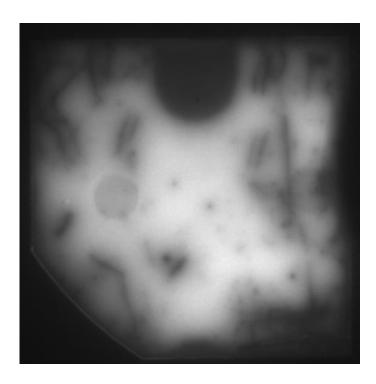




## **First PL images**



- Up to several hrs
- Typically 1mm per pixel

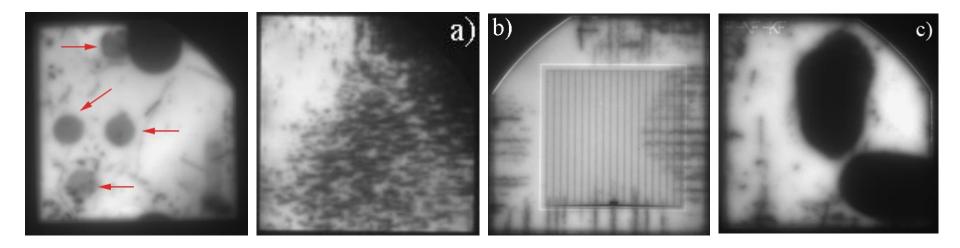


- 1s
- <100 μm per pixel





#### 2005: Qualitative PL imaging

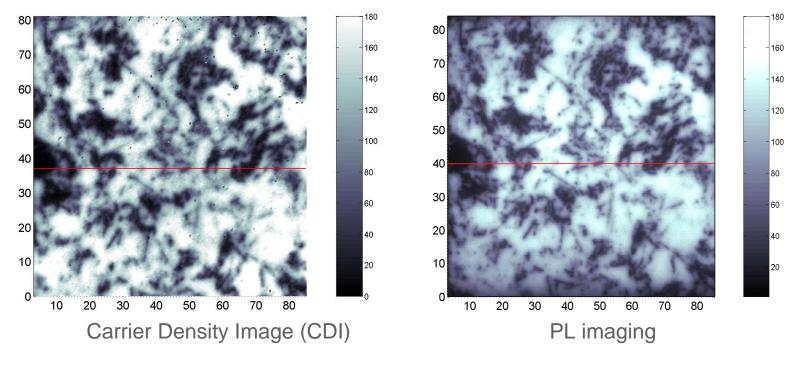


- Wide range of material- and process induced faults detectable
- **Rapid adoption** by the UNSW high efficiency group and the buried contact solar cell group for routine daily process monitoring





2006: Calibrated minority carrier lifetime images



Calibration via QSS-PC best option

T. Trupke, R.A. Bardos, M.C. Schubert and W. Warta, *Photoluminescence imaging of silicon wafers*, Appl.Phys.Lett. **89**, 044107 (2006).





## First paper – official birthday!

APPLIED PHYSICS LETTERS 89, 044107 (2006)

#### Photoluminescence imaging of silicon wafers

T. Trupke<sup>a)</sup> and R. A. Bardos

Centre of Excellence for Advanced Silicon Photovoltaics and Photonics, University of New South Wales, Sydney 2052, Australia

#### M. C. Schubert and W. Warta

Fraunhofer Institute for Solar Energy Systems, Heidenhofstrasse 2, D-79110 Freiburg, Germany

(Received 24 October 2005; accepted 4 June 2006; published online 26 July 2006)

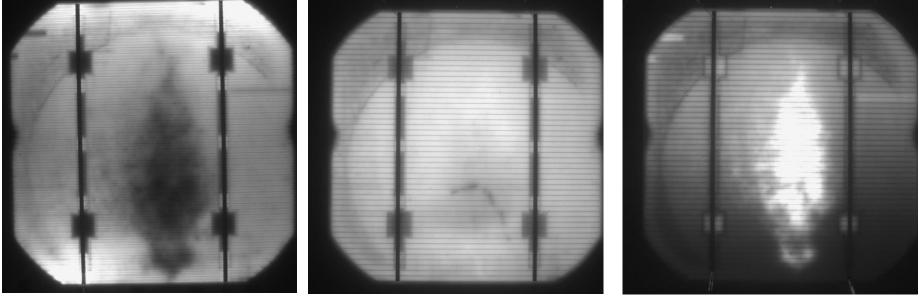








#### 2006: c-Si workshop, Denver



EL image

PL image

PL image with current extraction

- Proposal to use PL for R<sub>s</sub> imaging
- But why does this happen...?





Why do Rs variations within a cell show up in luminescence images?

$$I_{lum} \approx \exp\left(\frac{\Delta \eta - \hbar \omega}{kT}\right) \approx \exp\left(\frac{\Delta \eta}{kT}\right)$$

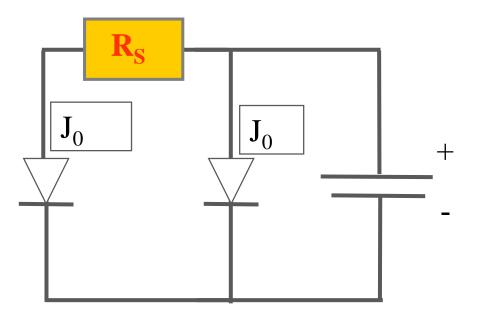
• EL: High Rs causes lower junction voltage



- **PL:** No current flow, no impact of Rs on junction voltage.
- **PL<sub>sc</sub>:** High Rs impedes local current extraction



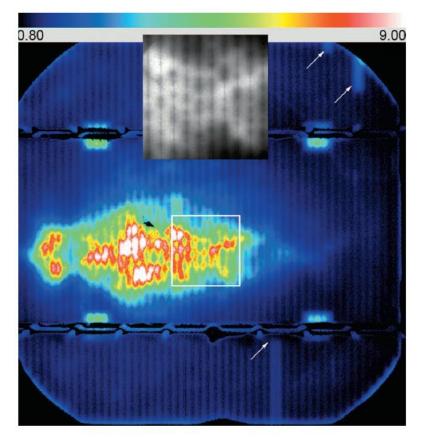
High relative PL intensity







#### 2007: Quantitative Rs imaging



- Rs imaging based on at least two images:
  - Voc
  - MPP
- Good separation of R<sub>s</sub> from lifetime
- Quantitative effective local R<sub>s</sub> in Ωcm<sup>2</sup>
- Several PL/EL based R<sub>s</sub> methods followed
- "PL emission at zero voltage! What the heck ...?"



"Voltage independent carriers"

T. Trupke, E. Pink, R. A. Bardos, and M. D. Abbott. Appl.Phys.Lett. **90**, 093508 (2007). H. Kampwerth, T. Trupke, J. Weber, Y. Augarten, Appl.Phys.Lett. **93**. 202102 (2008).





**2016:** Voltage independent carriers

• Presence of voltage independent carriers follows from the continuity equation:

$$\frac{d^2 n[x]}{dx^2} = \frac{n[x]}{L^2} - \frac{\alpha N_{\gamma} e^{-\alpha x}}{D}$$
$$n = C_a e^{\frac{x}{L}} + C_b e^{-\frac{x}{L}} + C_c e^{-\alpha x}$$
$$n = n_{\nu d} + n_{\nu i d}$$

- Voltage dependent term:
  - Voltage independent term:  $n_{vid} = (C_{a-vid})$

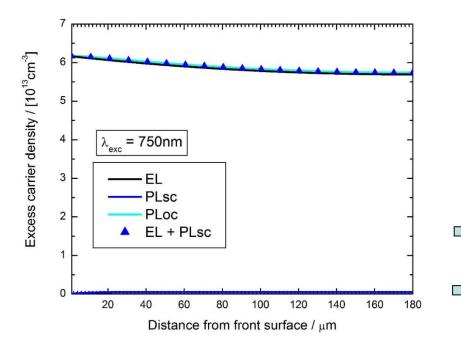
$$n_{vd} = \left(C_{a-vd}e^{\frac{x}{L}} + C_{b-vd}e^{\frac{-x}{L}}\right)e^{\frac{qV}{kT}},$$
  
$$n_{vd} = \left(C_{a-vid}e^{\frac{x}{L}} + C_{b-vid}e^{\frac{-x}{L}} + C_{c-vid}e^{-\alpha x}\right)N_{\gamma}$$

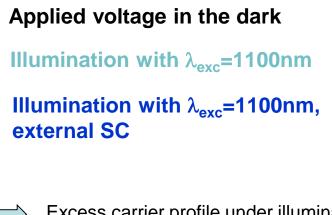
Mattias Juhl, manuscript submittted





#### 2016: Voltage independent carriers





- Excess carrier profile under illumination at SC is present at all bias conditions
- First order correction by subtracting PLsc from PL at other bias conditions.

#### Poster by Mattias Juhl at this workshop!





## Finding your place in the world

#### From 2007:

- PL imaging activities at UNSW, ANU, ISE, ISFH, NREL, Uni Konstanz, MPI, ISAS/JAXA...
  - Lifetime imaging and dynamic calibration methods
  - Series resistance imaging
  - Diffusion length imaging on cells
  - $J_0, J_{0e}$  imaging
  - J<sub>sc</sub> imaging
  - Efficiency imaging
  - Shunt detection and quantification
  - Bulk lifetime imaging on bricks
  - Fe (and other atomic defects) concentration imaging
  - High throughput as-cut wafer imaging
  - ...





## Finding your place in the world

#### Late 2007:

- Interest in PL imaging systems from industry after 2006 presentations (e.g. WCPEC 2006)
- BT imaging founded
  - Jørgen Nyhus from REC, first adopter (UNSW visit in Dec 2007, First PO for R1)!
  - LIS-R1 presented at 2008 EUPVSC, Milan.
  - Commercially availability PL imaging systems enable rapid adoption throughout PV industry.









## Finding your place in the world

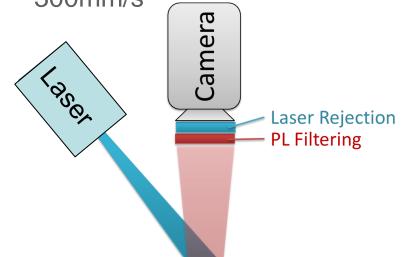
#### 2011: Line scanning PL imaging

# Luminescence Image

Area scanning

#### Line scanning

- Line illumination
- Measurement on the fly, e.g.
  300mm/s

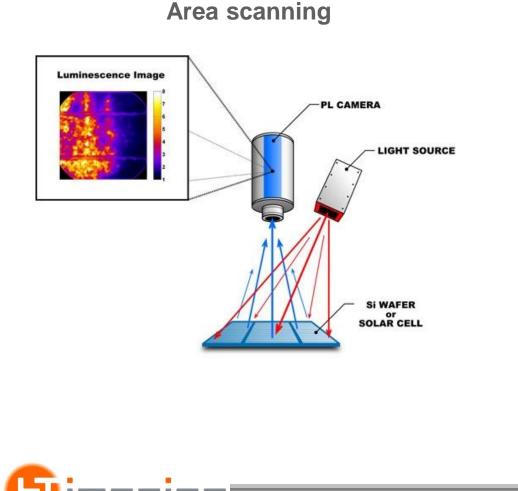






## Finding your place in the world

#### 2011: Line scanning PL imaging



#### Line scanning

Line illumination

Silicon Brick

Laser

Measurement on the fly, e.g.
 300mm/s

Camera

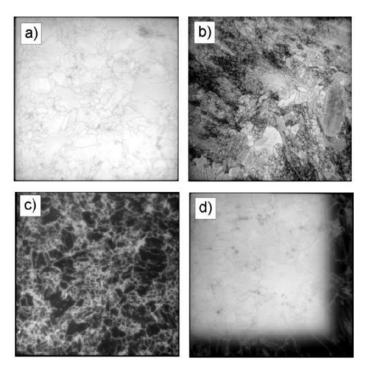
**Laser Rejection** 

**PL** Filtering

THE LINIV/FRSITY OF

# Growing up Finding your place in the world

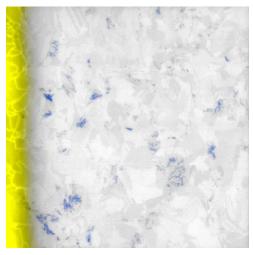
#### As cut wafer inspection



Metrics can be extracted from PL images using automatic image processing.



Dislocations



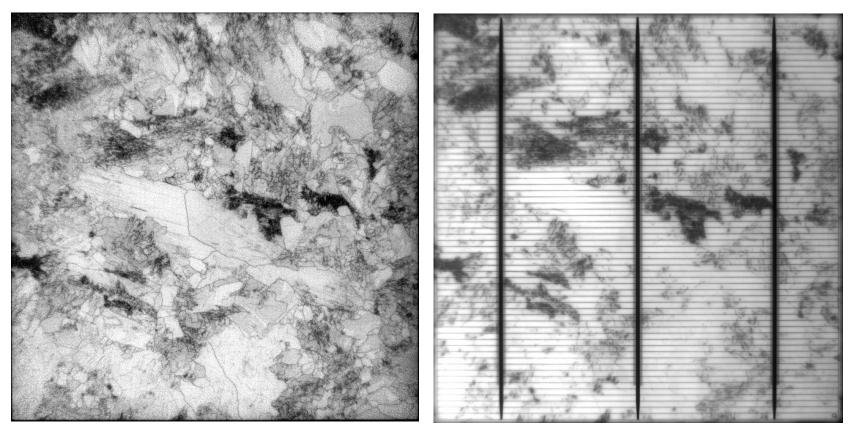
Impure edges





# **Growing up** Finding your place in the world

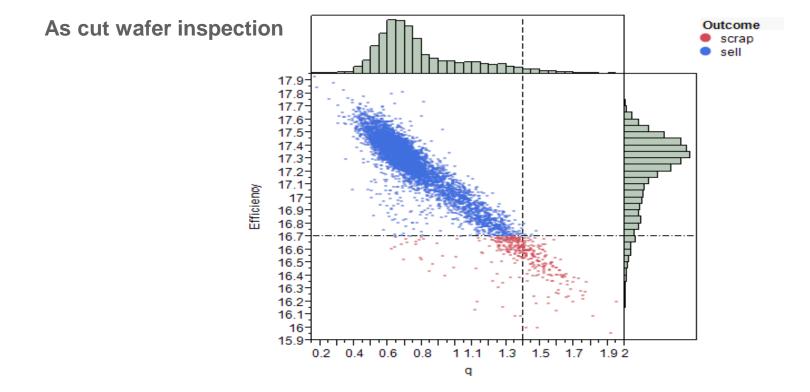
#### As cut wafer inspection







#### Finding your place in the world



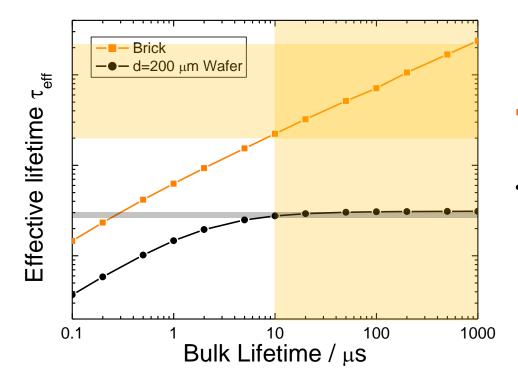
- PL imaging used today for IQC/OQC in production at up to 5,400 wph.
- Correlation of cell efficiency defect density with PL metrics
- Not detectable with sufficient throughput with any other technique.





# Growing up Finding your place in the world

2009: Brick inspection



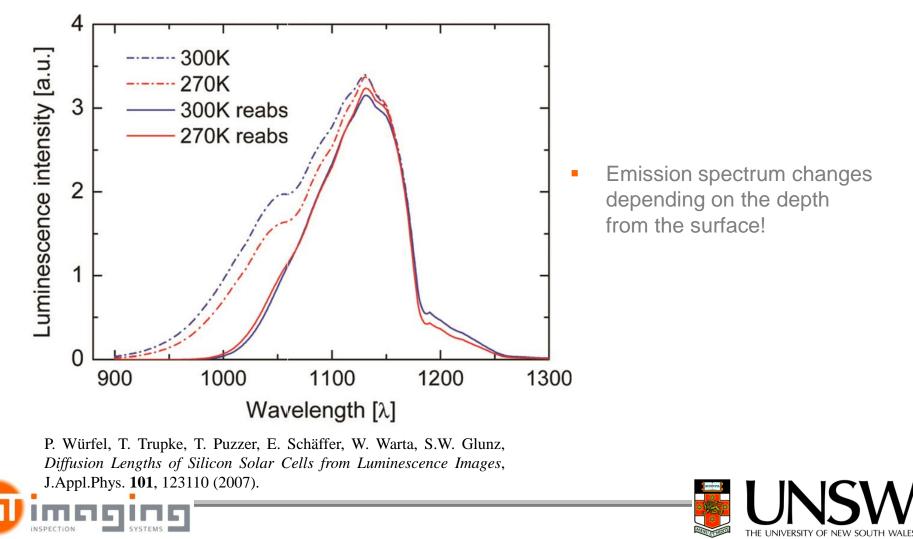
- Bulk lifetime dependence strongly non-linear.
- Virtually no variation for  $t_b > 10 \ \mu s$ .





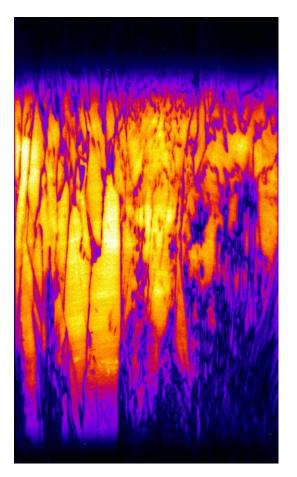
#### Finding your place in the world





# Growing up Finding your place in the world

2009: Brick inspection



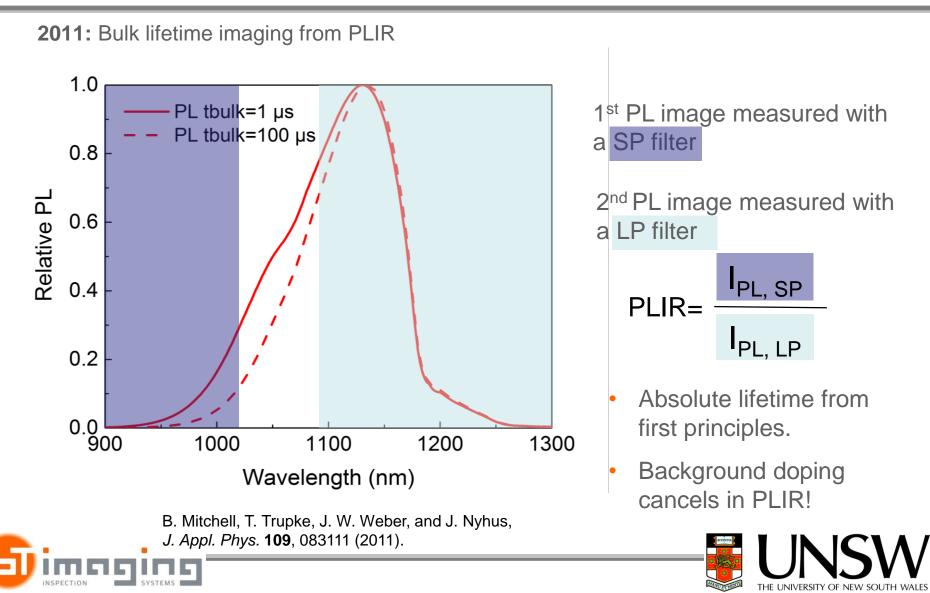


- PL imaging on bricks
- How to quantify?

$$I_{lum} \sim n \cdot p \approx \Delta n \cdot N_{D/A} = \tau_{eff} \cdot N_{D/A}$$



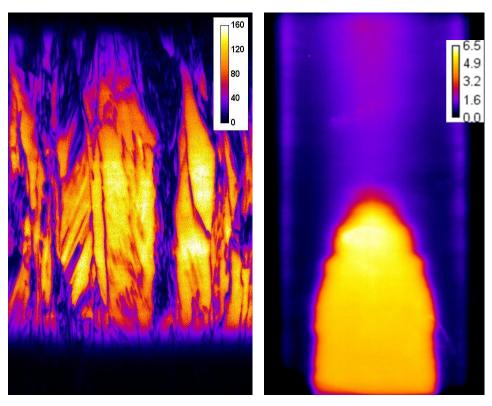
## Finding your place in the world



# Growing up Finding your place in the world

**2011:** Bulk lifetime imaging from PLIR

**p-type multi:** 0.2 μs < τ<sub>b</sub>



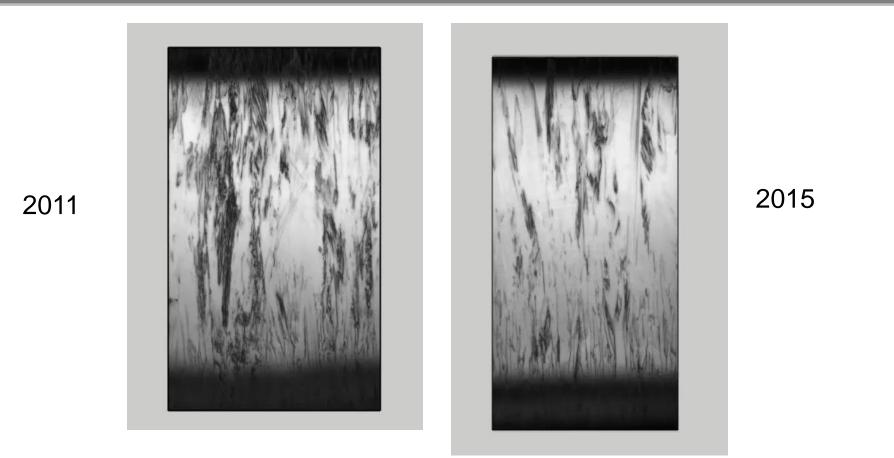
#### n-type Cz: Measured $\tau_{b}$ up to 7 ms

- Background doping variations cancel out in PLIR
- Bulk lifetime as quality specification for wafers
  - Cutting guide





#### Bulk lifetime on bricks and thick wafers



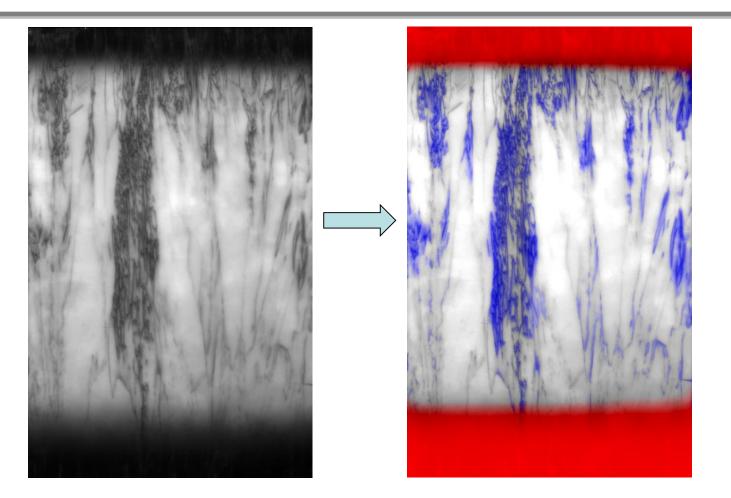
Structural defect analysis



D. Chung, B. Mitchell, J.W. Weber and T. Trupke, MRS Spring meeting 2016, Phoenix, USA, March 2016



#### Bulk lifetime on bricks and thick wafers



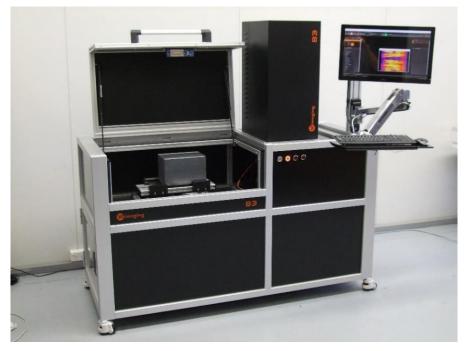
Automatic defect analysis





# Growing up Finding your place in the world

#### 2016: Bulk lifetime using line scan PL imaging



- Now in production
- Cutting guide
- Bulk lifetime and defect distribution for process development and process monitoring.







#### Now a teenager

Still a lot to learn...

#### LG25 in the TETB building

New playground for the PL group...









Australian Government

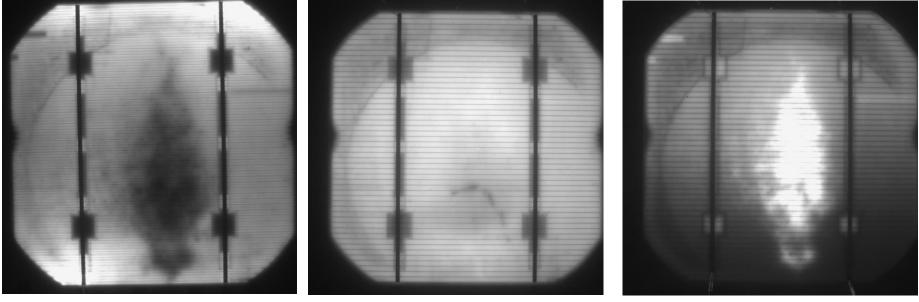
Australian Renewable Energy Agency





## Now a teenager Still a lot to learn...

#### 2006: c-Si workshop, Denver



EL image

PL image

PL image with current extraction

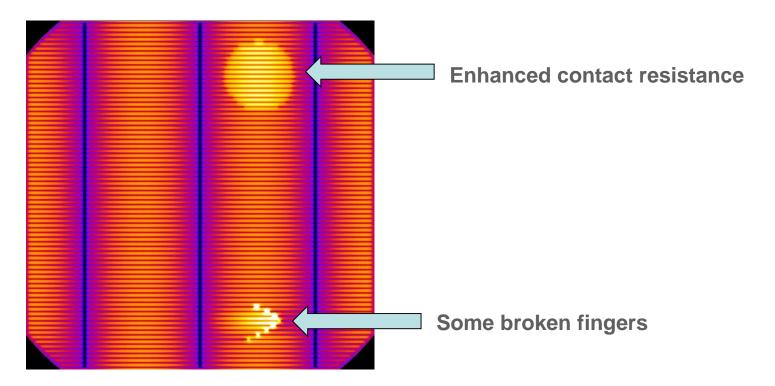
- Proposal to use PL for R<sub>s</sub> imaging
- But why does this happen...?





Still a lot to learn...

Solar cell with local Rs issues

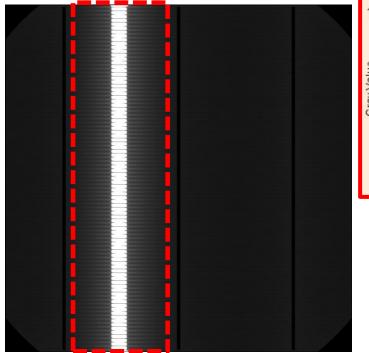


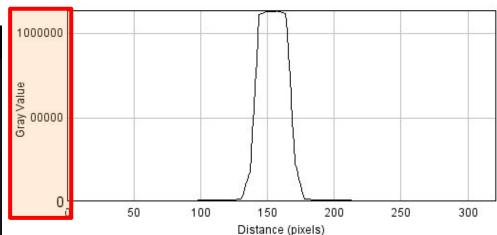




#### Still a lot to learn...

#### Line can PL imaging on cells





#### High illumination intensity: High PL contrast between illuminated and non illuminated areas

#### **Griddler<sup>1</sup> simulation**

<sup>1</sup> J. Wong, Griddler: Intelligent Computer Aided Design of Complex Solar Cell Metallization Patterns, 39th IEEE Photovoltaic Specialists Conference, Tampa, USA (2013).

All Griddler simulations by Iskra Zafirovska



#### Still a lot to learn...

#### 33 32 Gray Value 15 30 29 50 100 150 200 250 300 Distance (pixels) Low illumination intensity: Very efficient lateral current spreading

#### Line scan PL imaging on cells

Griddler<sup>1</sup> simulation

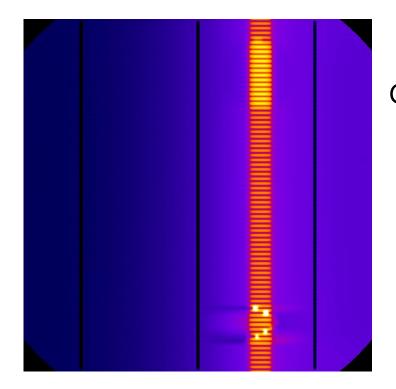
<sup>1</sup> J. Wong, Griddler: Intelligent Computer Aided Design of Complex Solar Cell Metallization Patterns, 39th IEEE Photovoltaic Specialists Conference, Tampa, USA (2013).

All Griddler simulations by Iskra Zafirovska



Still a lot to learn...

Line can PL imaging on cells



Griddler simulation: Line scanning PL image of c-Si solar cell with local Rs problems!

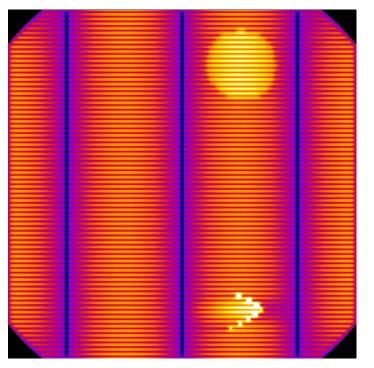
**Note:** this simulations represents just one snapshot in time from the line scanning PL imaging acquisition series.





Still a lot to learn...

Line can PL imaging on cells



Griddler simulation:

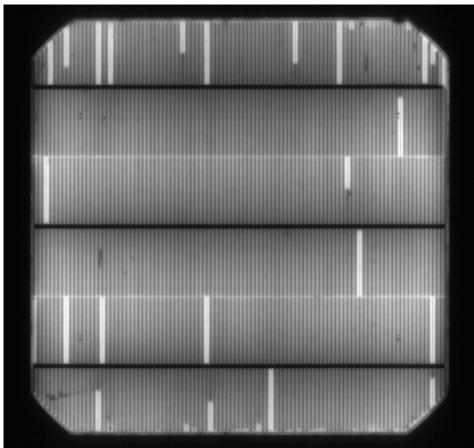
- Line scanning PL image of c-Si solar cell with local Rs problems!
- Similar contrast as in conventional PL images with current extraction.





Still a lot to learn...

Line can PL imaging on cells



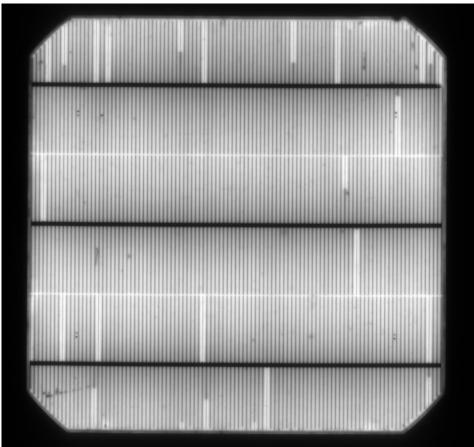
- Lowest illumination
- Busbars parallel to motion
- Strongest Rs effects





Still a lot to learn...

#### Line can PL imaging on cells



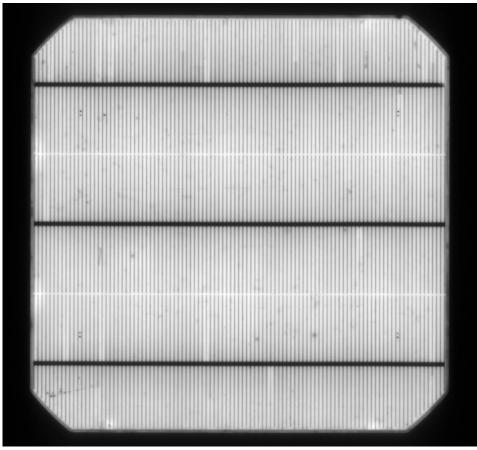
- Medium illumination
- Weaker contrast due to Rs effects





Still a lot to learn...

#### Line can PL imaging on cells



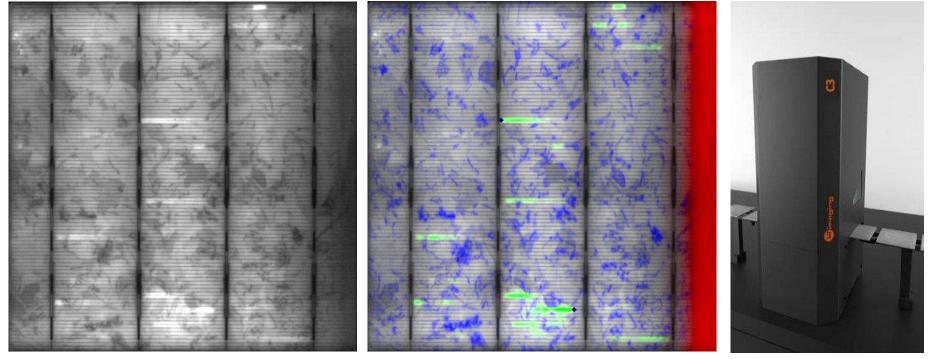
- Highest illumination
- Weak Rs effects





# Now a teenager Still a lot to learn...

#### Line can PL imaging on cells



**Inline PL image** 

Automatic Image algorithms

Contrast inversion facilitates image processing

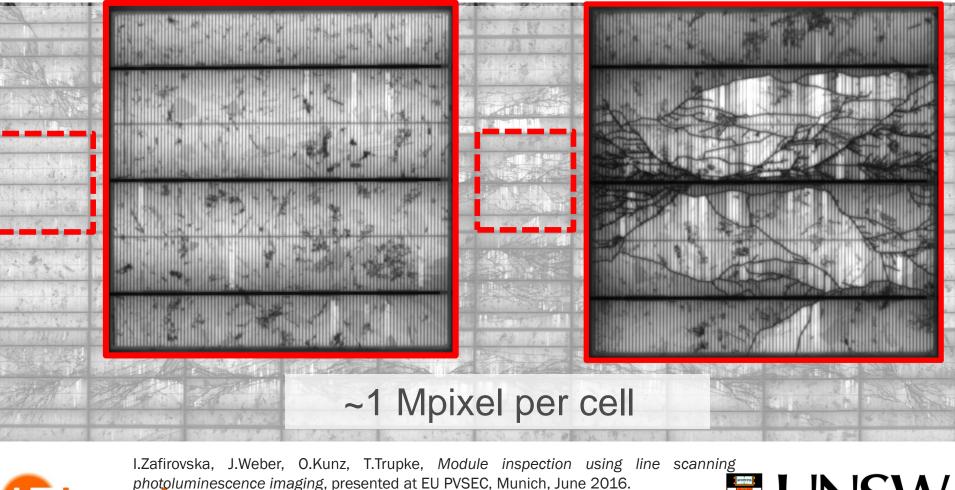




iLS-C3 PL module

Still a lot to learn...

#### PL imaging on modules





INSPECTION

SYSTEMS

#### Still a lot to learn...

**EL** image

#### Prototype of line scanning PL imaging system

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SYSTEMS

INSPECTION

#### Still a lot to learn...

#### **PL** image

Prototype of line scanning PL imaging system

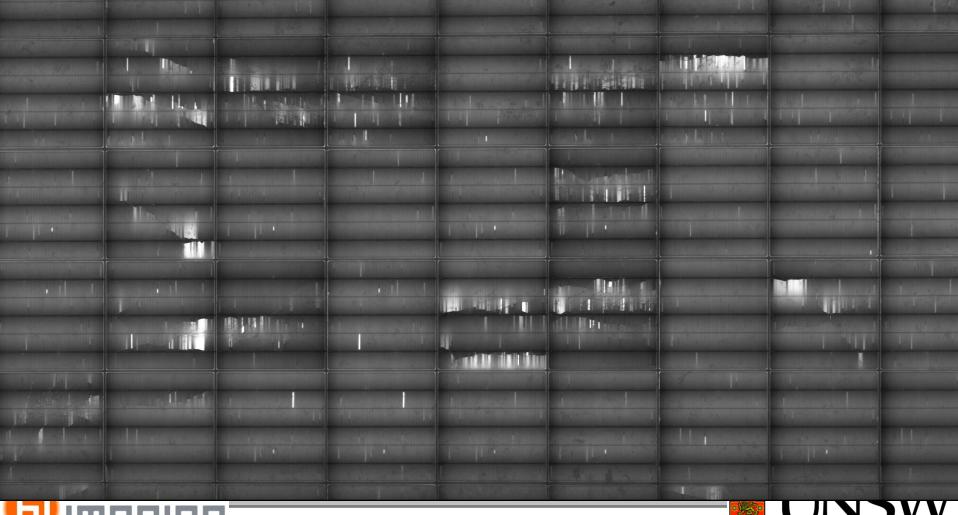
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#### Still a lot to learn...

#### **Processed image**

THE UNIVERSITY OF NEW SOUTH

Prototype of line scanning PL imaging system





Still a lot to learn...

Line can PL imaging on modules

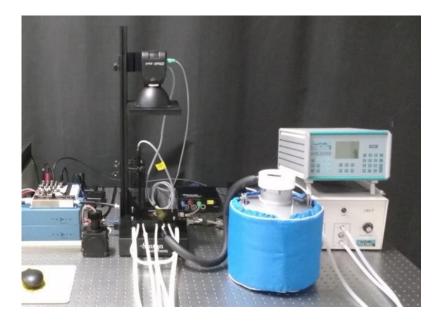






# Now a teenager Still a lot to learn...

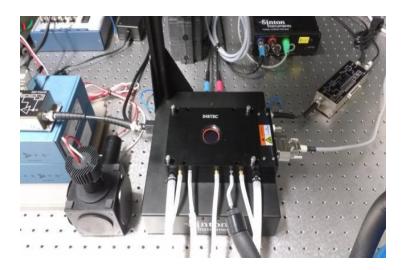
The mother of lifetime systems: TIDLS



#### Courtesy of Ziv Hameiri



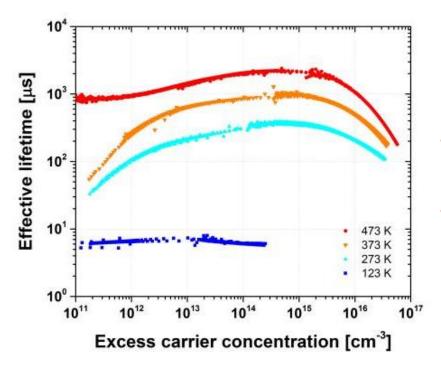
- -200 C to 400 C
- PL and PC detectors
- Various illumination sources
- Front and rear detection
- Corona charger





Still a lot to learn...

**Temperature dependent lifetime** 



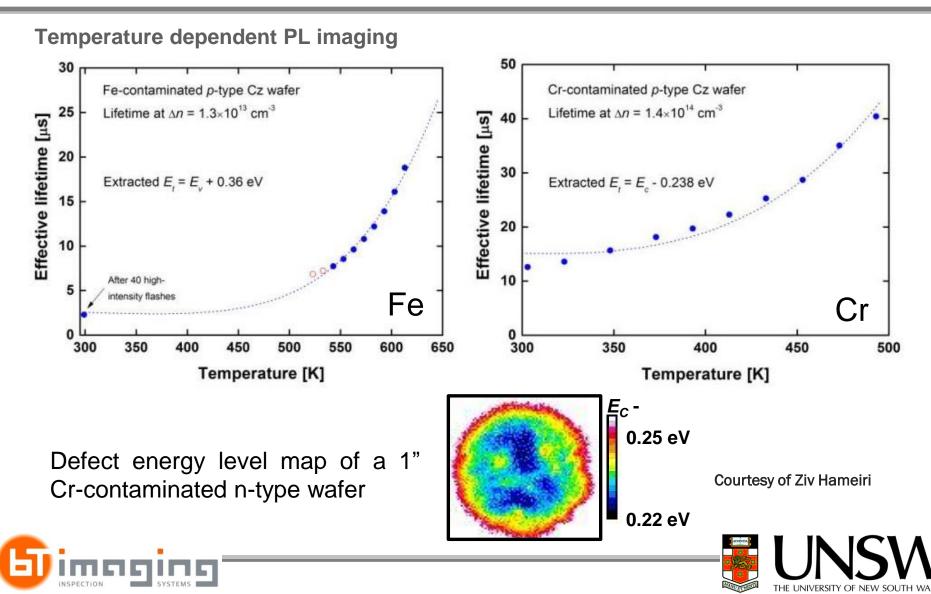
- Advanced defect characterisation using TIDLS
- Based on PL and/or PC data

**Courtesy of Mallory Jensen** 



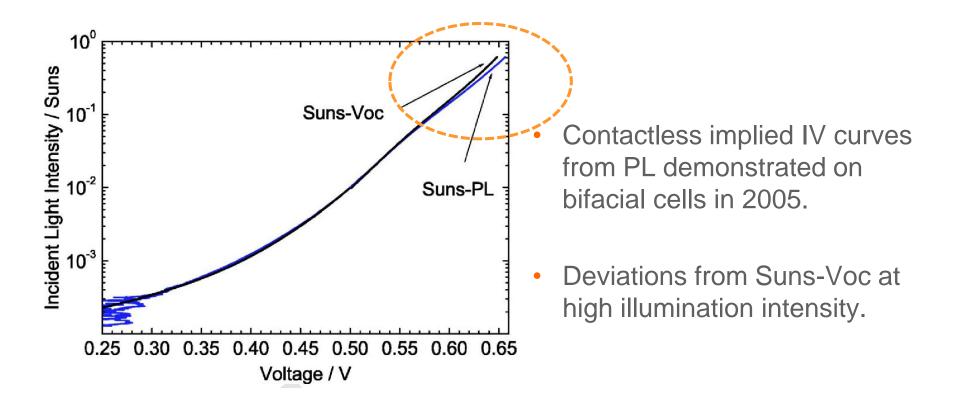


### Still a lot to learn...



Still a lot to learn...

Front detection PL, application to fully metalised cells

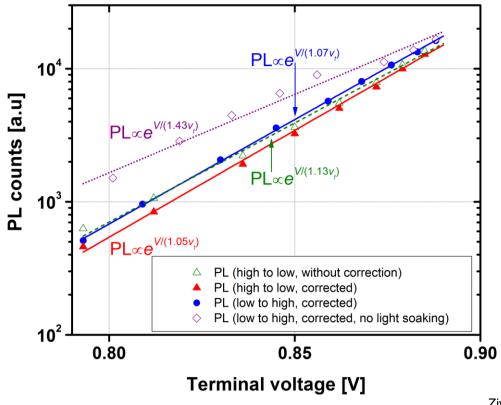


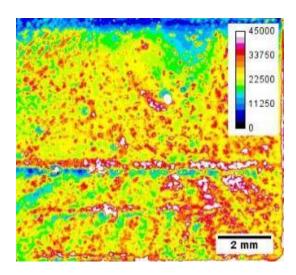
T. Trupke, R.A. Bardos, M.D. Abbott and J.E. Cotter, Appl.Phys.Lett. 87, 093503 (2005).



### Still a lot to learn...

#### PL imaging on Perovskites





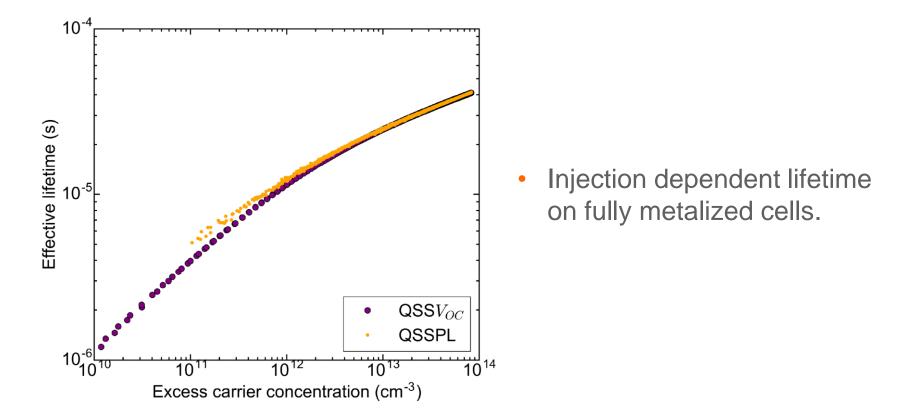
Ziv Hameiri, Arman M. Soufiani et al., *Photoluminescence and electroluminescence imaging of perovskite solar cells*, Prog.Photov. **23**, 1697 (2015).





#### Still a lot to learn...

Front detection PL, application to fully metalized cells



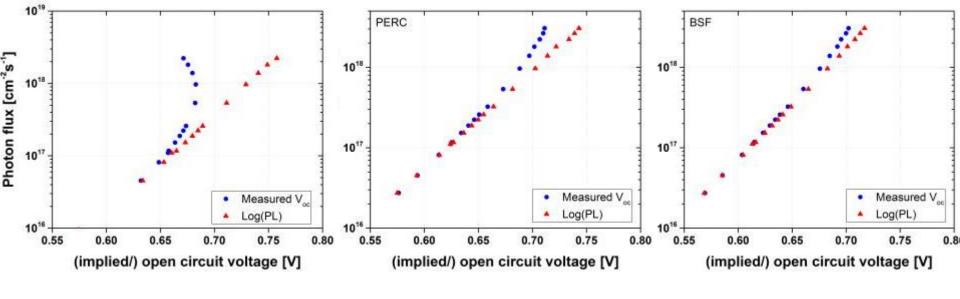
Courtesy of Robert Dumbrell, PhD candidate at UNSW





#### Still a lot to learn...

Front detection PL, application to fully metalized cells



LFC cell

PERC

Standard BSF cell

Suns-PL using front detection PL system

Courtesy of Robert Dumbrell, PhD candidate at UNSW





Still a lot to learn...

PL imaging with non-uniform illumination



- PL imaging system using Digital mirror device (DMD) for illumination
- Enables PL imaging with arbitrary non-uniform illumination
- Opens a new applications space!

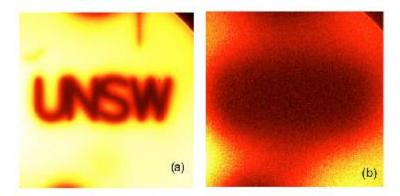


FIG. 4. (Color online) PL image  $(3.4 \times 3.4 \text{ cm}^2)$  of a monocrystalline silicon wafer which has locally been damaged by a laser, measured with (a)  $13 \times 10^{17} \text{ cm}^{-2} \text{ s}^{-1}$  (~5 Suns) and (b)  $2.5 \times 10^{16} \text{ cm}^{-2} \text{ s}^{-1}$  (0.1 Suns).



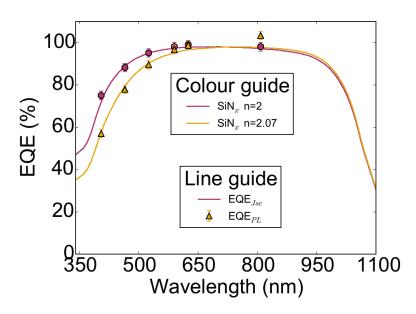


# Now a teenager Still a lot to learn...

PL imaging with variable illumination wavelengths



• PL imaging with LED illumination with 11 different illumination wavelengths.



Courtesy of Appu Paduthol, PhD candidate at UNSW





# Acknowledgement

- 10 years of development: PL imaging has come a long way.
- Long way to go!
- Thanks to the outstanding teams at UNSW and BTi, various industry partners and collaborators.
- UNSW team happy to collaborate!



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Thanks for listening...

